Contents

Foreword — VII

Author's premises — IX

Introduction — 1

1 2D topological insulators and quantum spin Hall states: what are they and which are the potential applications for the real world? — 3

1.1 Introduction — **3**

1.2 But indeed, in simple terms, what is a topological insulator (using quantum mechanics)? — **5**

1.3 How to move from the quantum Hall effect to the quantum spin Hall effect? (Intuitive explanation without mathematical developments) — **6**

1.4 Topological matter and topological invariant — **8**

1.4.1 What is the Chern number? — **8**

1.4.2 Z_2 invariant — **13**

1.5 The ideal case of graphene, which is not properly a topological insulator — **15**

1.6 Stanene: the real wonderful material for beyond CMOS — **18**

1.7 Topological insulators and thermoelectric effect: the game changer? — **21**

1.8 Theoretical parameters influencing thermoelectric effect in topological insulators — **23**

1.9 Conclusions — **28**

References — **29**

2 Magic angle: twisting graphene layers to create superconductors — 33

2.1 Introduction — **33**

2.2 A brief history of superconductivity — **34**

2.3 The discovery of the magic angle: the prediction — **37**

2.4 The experimental results and evidence of unconventional superconductivity — **41**

2.5 What happens if we pile up three layers? — **48**

2.6 Conclusions and perspectives — **51**

References — **52**

Bibliografische Informationen
http://d-nb.info/1245231618

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3 Valleytronics and a new way to encode information using 2D materials — 55
3.1 Valleytronics: basic science behind and interest — 55
3.2 Which materials for valleytronics? — 56
3.3 Optical stimulus: the right way to encode valley pseudo-spin? — 59
3.4 Potential implementation of valleytronics: what are the main challenges? — 63
3.5 Some examples of applications and perspectives — 66
References — 67

4 2D black phosphorus: difficult to handle but so interesting for opto-electronics — 71
4.1 Introduction — 71
4.2 Different allotropic forms and structures of phosphorus — 72
4.3 Why BP is so interesting? Tailoring the band gap through thickness — 74
4.4 Passivation — 78
4.4.1 Encapsulation — 79
4.4.2 Functionalization — 80
4.4.3 Liquid-phase surface passivation — 85
4.4.4 Doping — 86
4.5 Some examples of potential applications — 88
4.5.1 Few layer BP in field-effect transistors — 88
4.5.1.1 Introduction — 88
4.5.1.2 Examples of BP-based transistors: some pioneering works — 89
4.5.2 Energy storage applications — 92
4.5.2.1 Solar cells — 92
4.5.3 Energy storage applications — 95
4.5.3.1 Batteries (lithium ion) — 95
4.5.3.2 Supercapacitors — 96
4.6 Conclusions — 96
References — 99

5 Straintronics: a new way to engineer the physical intrinsic properties of 2D materials and van der Waals structures — 105
5.1 Introduction — 105
5.2 What type of strain and what are the main effects? — 107
5.3 In-plane strain: some examples in different fields — 108
5.4 Out-of-plane strain — 118

5.5 Heterostrain — 122
5.6 Conclusions and perspectives — 124
References — 125

6 Exotic properties of 2D materials: where are we? The compromise between beyond CMOS and more-than-Moore vision and roadmaps — 129
6.1 Premises to conclusion and to overall analysis — 129
6.2 Short introduction on the meaning of "Moore's law", "more-than-Moore" and "beyond CMOS" vision — 129
6.3 Some considerations — 131
6.4 Roadmaps — 134
6.5 Topological insulators and thermoelectric — 134
6.6 Magic angle and superconductivity — 136
6.7 Valleytronics and information storage — 136
6.8 Black phosphorus and optoelectronics — 137
6.9 Straintronics and different potential implementations — 138
6.10 Classification of the potential innovations — 139
References — 141

Index — 143